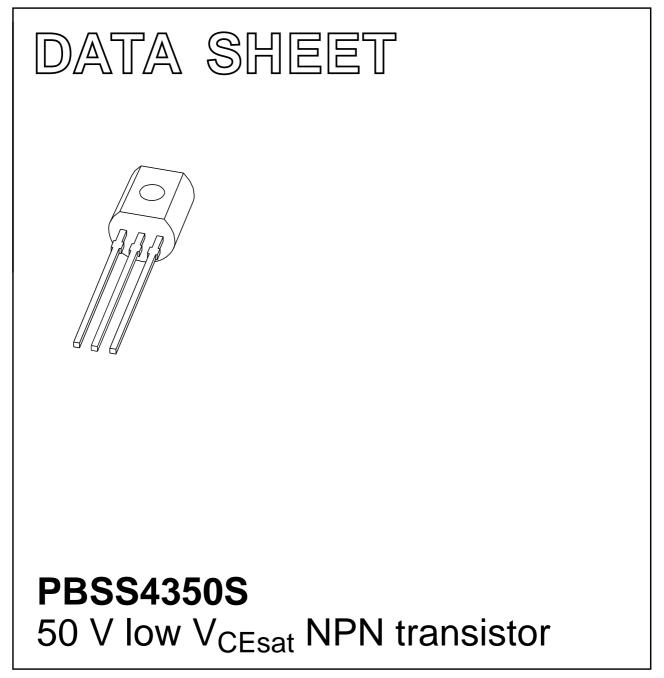
# DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 2001 Nov 19

2004 Aug 20



### **PBSS4350S**

#### FEATURES

- High power dissipation (830 mW)
- Ultra low collector-emitter saturation voltage
- 3 A continuous current
- High current switching
- Improved device reliability due to reduced heat generation.

#### APPLICATIONS

- Medium power switching and muting
- Linear regulators
- DC/DC convertor
- Supply line switching circuits
- Battery management applications
- Strobe flash units
- Heavy duty battery powered equipment (motor and lamp drivers).

#### DESCRIPTION

NPN low V<sub>CEsat</sub> transistor in a SOT54 plastic package. PNP complement: PBSS5350S.

#### MARKING

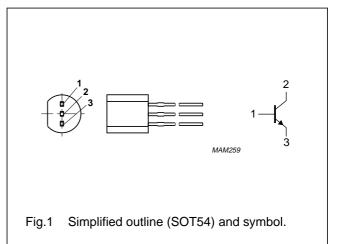
TYPE NUMBER	MARKING CODE		
PBSS4350S	S4350S		

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT	
V <sub>CEO</sub>	V <sub>CEO</sub> collector-emitter voltage			
I <sub>C</sub>	I <sub>C</sub> collector current (DC)		А	
I <sub>CM</sub> peak collector current		5	А	
R <sub>CEsat</sub> equivalent on-resistance		<145	mΩ	

#### PINNING

PIN	DESCRIPTION	
1	base	
2	collector	
3	emitter	



#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	60	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	6	V
I <sub>C</sub>	collector current (DC)		_	3	А
I <sub>CM</sub>	peak collector current		_	5	A
I <sub>BM</sub>	peak base current		-	1	A
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	830	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Note

1. Device mounted on a printed-circuit board, single sided copper, tinplated and standard footprint.

### **PBSS4350S**

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	in free air; note 1	150	K/W

#### Note

1. Device mounted on a printed-circuit board, single sided copper, tinplated and standard footprint.

#### CHARACTERISTICS

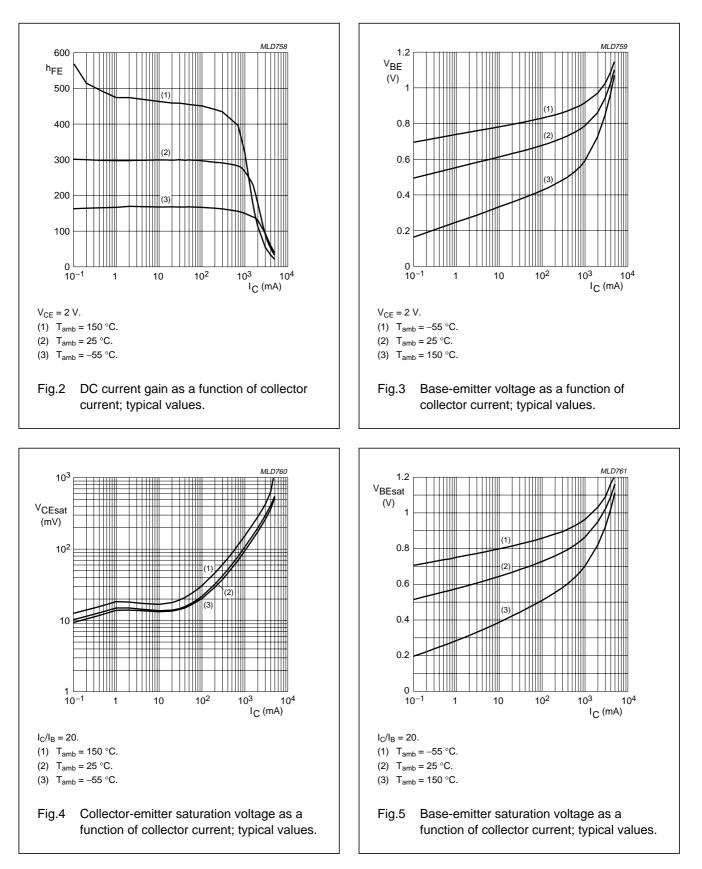
 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0$	-	-	100	nA
		V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0; T <sub>j</sub> = 150 °C	-	-	50	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0$	_	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA	200	-	-	
		$V_{CE} = 2 V; I_{C} = 1 A;$ note 1	200	-	_	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 2 A; note 1	100	-	-	
V <sub>CEsat</sub>	collector-emitter saturation	I <sub>C</sub> = 500 mA; I <sub>B</sub> = 50 mA	-	-	90	mV
voltage	voltage	I <sub>C</sub> = 1 A; I <sub>B</sub> = 50 mA	-	-	170	mV
		I <sub>C</sub> = 2 A; I <sub>B</sub> = 200 mA; note 1	-	-	290	mV
R <sub>CEsat</sub>	equivalent on-resistance	I <sub>C</sub> = 2 A; I <sub>B</sub> = 200 mA; note 1	-	110	<145	mΩ
V <sub>BEsat</sub>	base-emitter saturation voltage	I <sub>C</sub> = 2 A; I <sub>B</sub> = 200 mA; note 1	-	-	1.2	V
V <sub>BEon</sub>	base-emitter turn-on voltage	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 1 A; note 1	-	-	1.1	V
f <sub>T</sub>	transition frequency	I <sub>C</sub> = 100 mA; V <sub>CE</sub> = 5 V; f = 100 MHz	100	-	_	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = I_e = 0; f = 1 \text{ MHz}$	_	-	30	pF

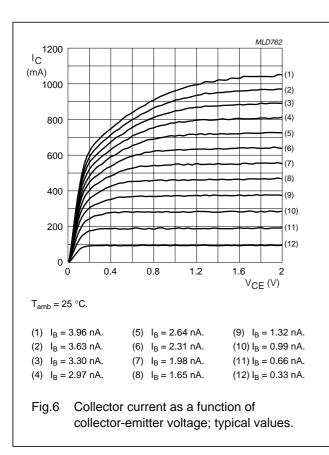
#### Note

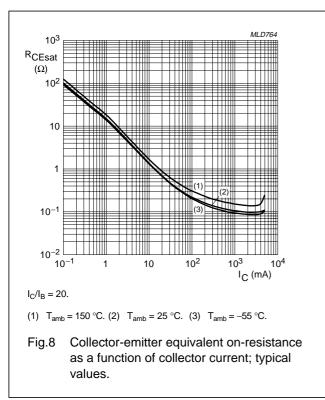
1. Pulse test:  $t_p \leq 300 \ \mu s; \ \delta \leq 0.02.$ 

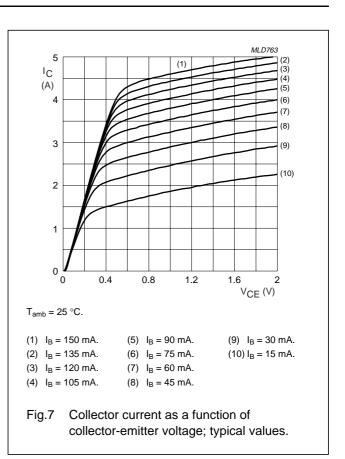
### PBSS4350S



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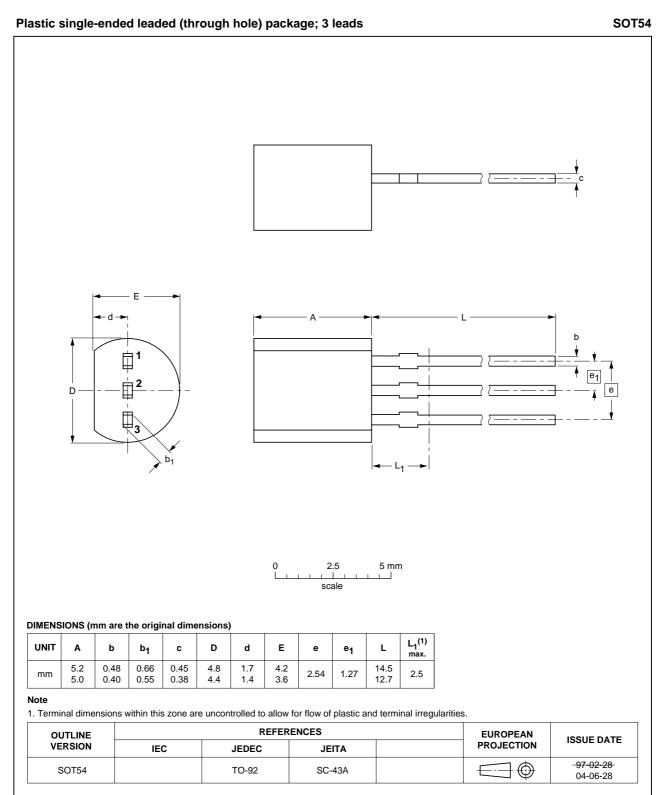




**PBSS4350S** 

# 50 V low V<sub>CEsat</sub> NPN transistor

#### PACKAGE OUTLINE



PBSS4350S

#### DATA SHEET STATUS

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)(3)</sup>	DEFINITION
1	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
11	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

#### DEFINITIONS

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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